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View Online at https://aerobasegroup.com/nsn/5961-01-589-4827

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Inclosure Material:	
Glass	
Overall Length:	
Between 2.155 inches ar	id 3.155 inches
Terminal Length:	
Between 1.000 inches ar	id 1.500 inches
Overall Diameter:	
Between 0.060 inches ar	ld 0.090 inches
Function For Which De	signed:
Zener diode	
End Application:	
5841-01-552-8119	
Joint Electronic Device	Engineering Council/jedec/case Outline Designation:
Do-35	
Mounting Method:	
Terminal	
Terminal Circle Diamet	er:
0.020 inches	
Semiconductor Materia	l:
Silicon	
Voltage Rating In Volts	Per Characteristic:
9.1 regulator voltage	
Voltage Tolerance In Pe	ercent:
-5.0/+5.0	
Current Rating Per Cha	racteristic:
47.00 milliamperes dc c	urrent in reverse breakdown region
Power Rating Per Char	acteristic:
500.0 milliwatts total pov	ver dissipation
Maximum Operating Te	mpurature Per Measurement Point:
175.0 degrees celsius ar	nbient air
Test Data Document:	
81349-mil-prf-19500 spe	cification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes comme	ercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and perfor	mance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Qua	intity:
2 uninsulated wire lead	
Specification Data:	
81349-mil-prf-19500/533	government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	

No

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Fiig: A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.